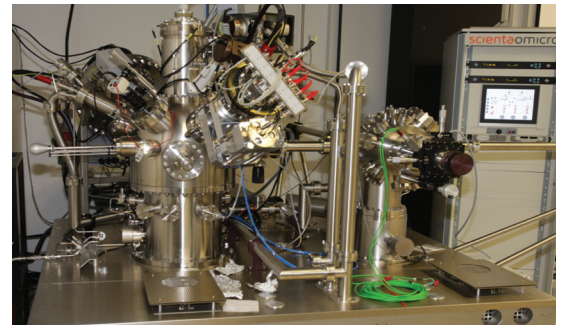


# Surface analysis UHV system

## NanoSAM Lab

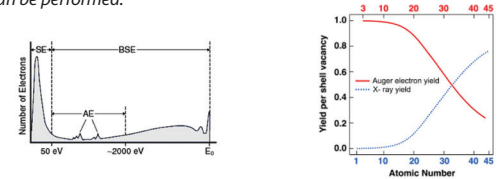
### DESCRIPTION

The Nano SAM Lab is a dedicated surface analysis UHV system for high resolution structural and chemical analysis by Scanning Auger Microscopy (SAM), Scanning Electron Microscopy (SEM) and Secondary Electron Microscopy with Polarization Analysis (SEMPA) for the characterization of the magnetic domain structure. The instrument is designed for use together with UHV Gemini high resolution electron column. It includes Matrix software and electronics for static Auger spectroscopy (AES) and SAM. In combination with UHV Gemini, Matrix provides an unsurpassed drift correction technology based on autocorrelation of subsequent SEM images. This opens up the possibility to perform long term AES measurements on very small features with low intensity, or elemental resolved SAM maps of nanostructures with a low concentration of elements of interest and/or low sensitivity factors. The NanoSAM Lab is equipped with high precision goniometer - mounted four axis UHV stage for the combination of high resolution SEM, SAM and SEMPA, which allows heating up to 750 K. Moreover, the NanoSAM Lab embodies preparation chamber which comprises a manipulator with the possibility of heating the sample to 1500 °C by resistive heating and 900 °C by radiative heating. The preparation chamber contains 8 flanges for user extensions.

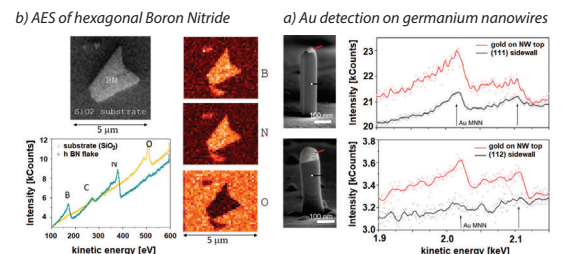


### AES

AES provides quantitative elemental and chemical state information from surfaces of solid materials usually in the area of material science. Focused electron beam scans across the sample surface which leads to the production of various signals including the emission of 'Auger' electrons. An electron energy analyzer measures the kinetic energies of the emitted Auger electrons, which are characteristic for elements present within the top 1-5 nm of the sample and intensity of an Auger peak. Hence, the identity and quality of a detected element can be determined. When used in combination with sputtering ion source, compositional depth profiling can be performed.

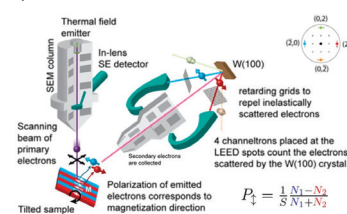


### Chemical Composition Determination



### SEMPA

SEMPA is a technique for direct characterization of the magnetic domain structure of a sample. Spin polarization of the secondary electrons (emitted by the primary beam) corresponds to the magnetization direction in the material and can be measured in order to create a magnetization map of the sample. Spin detection is based on the SPLEED (Spin Polarized Low Energy Electron Diffraction) principle, i.e. diffraction from a single crystal surface of  $W(100)$  forming a few well defined diffraction spots - (LEED) spots.

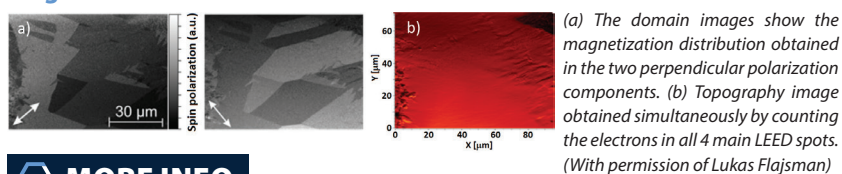


The LEED spots exhibits intensity variations and asymmetries that depend on the energy and degree of spin polarization of the scattered electrons.

### SPECIFICATION

SEM		SAM	
<b>Electron Column</b>	UHV Gemini (FEG)	<b>SEM-SAM Coincidence at</b>	~ 22 mm
<b>Emitter</b>	Schottky cathode	<b>SEM-SAM Angle at</b>	+30°
<b>Acceleration Voltage</b>	100 V – 20 kV	<b>Lateral Resolution (@ 1nA)</b>	< 6 nm @ 10 keV < 10 nm @ 5 keV
<b>Probe Current</b>	min. 50 nA @ 15 keV min. 28 nA @ 3 keV	<b>Analyzer Resolution</b>	> 420 KCPS no background
<b>Detectors</b>	Inlens SE detector	<b>Image Drift</b>	< 10 nm/10 hrs
<b>Resolution</b>	< 3 nm @ 15 keV < 13 nm @ 1 keV	SEMPA	
<b>Specimen Stage Movements</b>	XYZ: 10×10×10 mm Tilt: -60° to +60°	<b>SEM-SEMPA Angle at</b>	-60°
<b>Stage Heating</b>	Up to 750 K	<b>Resolution</b>	< 50 nm
<b>Maximum Sample Size</b>	12×15×4 mm <sup>3</sup>	<b>Image Drift</b>	< 10 nm/10 hrs
<b>Basic pressure</b>	< 3 e-10 mbar	<b>Detectors</b>	Rotation Detector
<b>Image drift compensation</b>		Ion Source/ Charge Neutralization	
<b>4 electrical contacts up to 6 Ghz</b>		<b>Neutralization</b>	10 eV - 5 keV ions @1 - 5 keV > 2 mA/cm <sup>2</sup>
<b>Preparation chamber</b>		<b>Ion Sputtering</b>	min. 100 nA @ 15 eV

### Magnetic domains of Iron Whisker



### MORE INFO

**Guarantor:** Marek Otevřel (marek.otevrel@ceitec.vutbr.cz)

**Web:** <http://nano.ceitec.cz/scanning-electron-microscopy-with-polarization-analysis-scienta-omicron-nanosam-lab/>

